

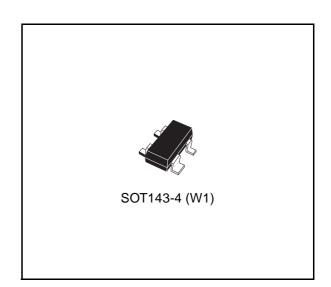
STM6315

Open Drain Microprocessor Reset

PRELIMINARY DATA

Features Summary

- GUARANTEED RST ASSERTION DOWN TO $V_{CC} = 1.0V (-40^{\circ}C \text{ to } 85^{\circ}C)$
- OPEN-DRAIN RST OUTPUT CAN EXCEED
- ±1.8% RESET THRESHOLD ACCURACY (25°C)
- POWER SUPPLY TRANSIENT IMMUNITY
- LOW SUPPLY CURRENT 5µA (typ)
- OPERATING TEMPERATURE: -40°C TO 125°C
- AVAILABLE IN SOT143-4 PACKAGE



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STM6315 1 Summary Description

1 Summary Description

The STM6315 Microprocessor Reset Circuit is a low power supervisory device used to monitor power supplies. It performs a single function: asserting a reset signal whenever the V_{CC} supply voltage drops below a preset value and keeping it asserted until V_{CC} has risen above the preset threshold for a minimum period of time (t_{rec}). It also provides a manual reset input (\overline{MR}). The open drain \overline{RST} output can be pulled up to a voltage higher than V_{CC} , but less than 6V.

The STM6315 comes with standard factory-trimmed reset thresholds of 2.63V, 2.93V, 3.08V, 4.38V, and 4.63V. The STM6315 is available in the SOT143-4 package.

Figure 1. Logic Diagram

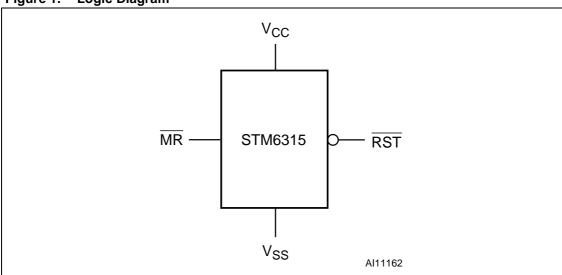
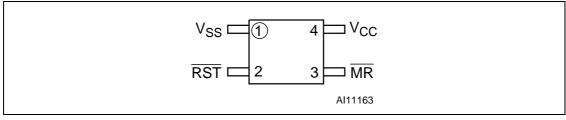


Table 1. Signal Names

Symbol	Description
V _{CC}	Supply Voltage
MR	Manual Reset Input
RST	Active-low Open Drain Reset Output
V _{SS}	Ground

Figure 2. SOT143-4 Connections (Top View)



1 Summary Description STM6315

Figure 3. Block Diagram

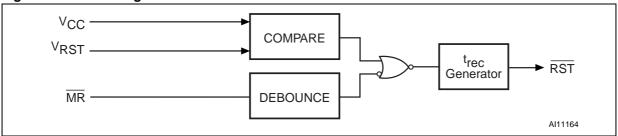
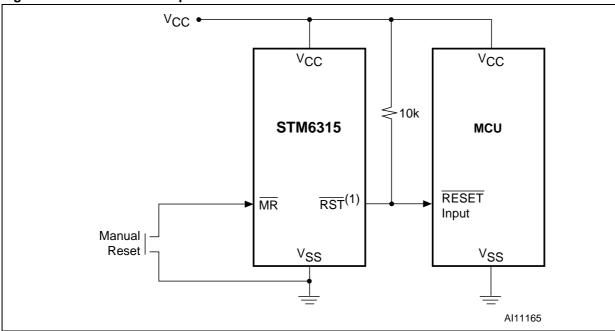


Figure 4. Hardware Hookup



1. Open drain $\overline{\text{RST}}$ output requires external pull-up resistor.

STM6315 2 Operation

2 Operation

2.1 Reset Output

The STM6315 Microprocessor Reset Circuit has an active-low, open drain reset output. This output structure will sink current when $\overline{\text{RST}}$ is asserted. Connect a pull-up resistor from $\overline{\text{RST}}$ to any supply voltage up to 6V (see *Figure 4 on page 6*). Select a resistor value large enough to register a logic low, and small enough to register a logic high while supplying all input current and leakage paths connected to the reset output line. A 10k pull-up is sufficient in most applications.

The STM6315 asserts a reset signal to the MCU whenever V_{CC} goes below the reset threshold (V_{RST}) , or when the manual reset input (\overline{MR}) is taken low (see *Figure 5* and *Figure 6 on page 8*). \overline{RST} is guaranteed valid down to $V_{CC} = 1.0V$ ($-40^{\circ}C$ to $+85^{\circ}C$).

During power-up, (once V_{CC} exceeds the reset threshold) an internal timer keeps \overline{RST} low for the reset time-out period, t_{rec} . After this interval, \overline{RST} returns high.

If V_{CC} drops below the reset threshold, \overline{RST} goes low. Each time \overline{RST} is asserted, it stays low for at least the reset time-out period. Any time V_{CC} goes below the reset threshold, the internal timer clears. The reset timer starts when V_{CC} returns above the reset threshold.

2.2 Manual Reset Input

A logic low on $\overline{\text{MR}}$ asserts $\overline{\text{RST}}$. $\overline{\text{RST}}$ remains asserted while $\overline{\text{MR}}$ is low, and for t_{rec} after it returns high. The $\overline{\text{MR}}$ input has an internal pull-up resistor $63\text{k}\Omega$ (typ), allowing it to be left open if not used.

This input can be driven with TTL/CMOS-logic levels or with open drain/collector outputs. Connect a standard open push-button switch from $\overline{\text{MR}}$ to V_{SS} to create a manual reset function (see *Figure 4 on page 6*); external debounce circuitry is not required. If the device is used in a noisy environment, connect a 0.1µF capacitor from $\overline{\text{MR}}$ to V_{SS} to provide additional noise immunity.

2.3 Negative-Going V_{CC} Transients

The STM6315 is relatively immune to negative-going V_{CC} transients (glitches). *Figure 13 on page 12* shows typical transient duration versus reset comparator overdrive (for which the STM6315 will NOT generate a reset pulse). The graph was generated using a negative pulse applied to V_{CC} , starting at 0.5V above the actual reset threshold and ending below it by the magnitude indicated (Reset Threshold Overdrive). The graph indicates the maximum pulse width a negative V_{CC} transient can have without causing a reset pulse. As the magnitude of the transient increases (further below the threshold), the maximum allowable pulse width decreases. Any combination of duration and overdrive which lies under the curve will NOT generate a reset signal (see *Figure 13*). A 0.1 μ F bypass capacitor mounted as close as possible to the V_{CC} pin provides additional transient immunity.

2 Operation STM6315

2.4 Valid \overline{RST} Output Down to $V_{CC} = 0V$

When V_{CC} falls below 1V, the \overline{RST} output no longer sinks current, but becomes an open circuit. In most systems this is not a problem, as most MCUs do not operate below 1V. However, in applications where \overline{RST} output must be valid down to 0V, a pull-down resistor may be added to hold the \overline{RST} output low. This resistor must be large enough to not load the \overline{RST} output, and still be small enough to pull the output to Ground. A 100K Ω resistor is recommended.

Figure 5. Reset Timing Diagram

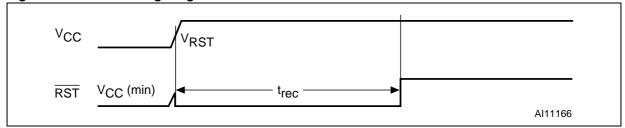
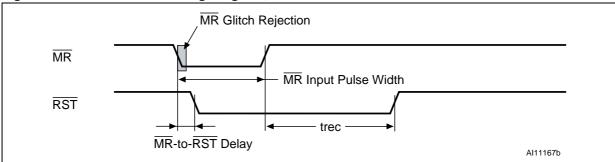


Figure 6. Manual Reset Timing Diagram, Switch Bounce/Debounce



3 Typical Operating Characteristics

Note: Typical values are at $T_A = 25$ °C.

Figure 7. Supply Current vs. Supply Voltage

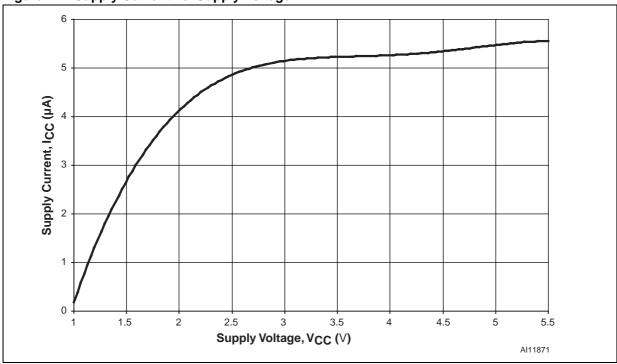


Figure 8. Supply Current vs. Temperature (No load)

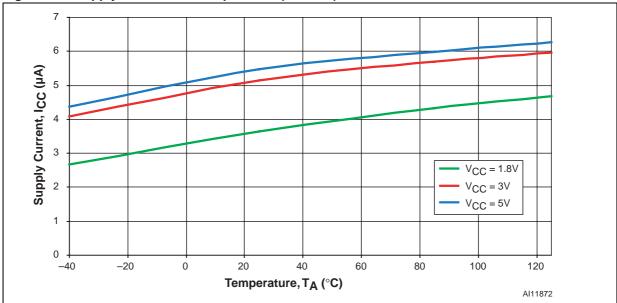


Figure 9. RST Output Voltage vs. Output Current

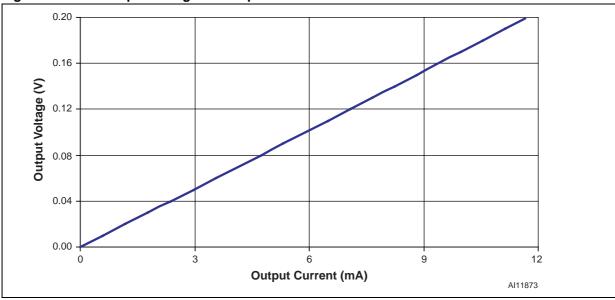
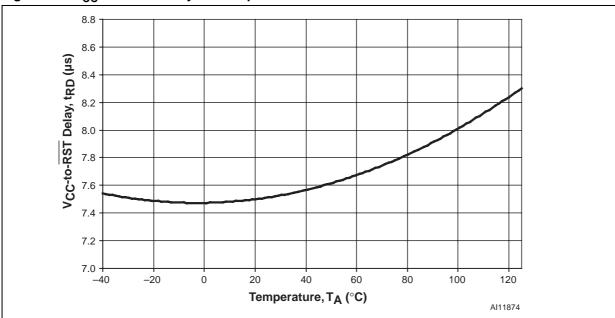


Figure 10. V_{CC}-to-Reset Delay vs. Temperature



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Figure 11. Normalized Reset Time-out Period vs. Temperature

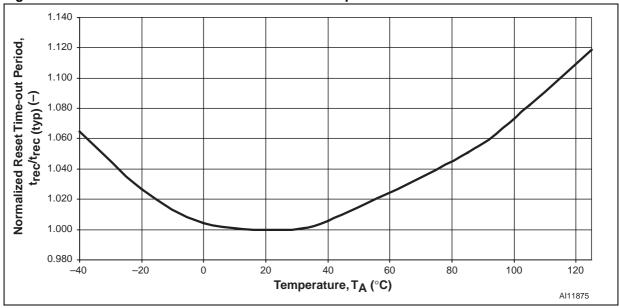
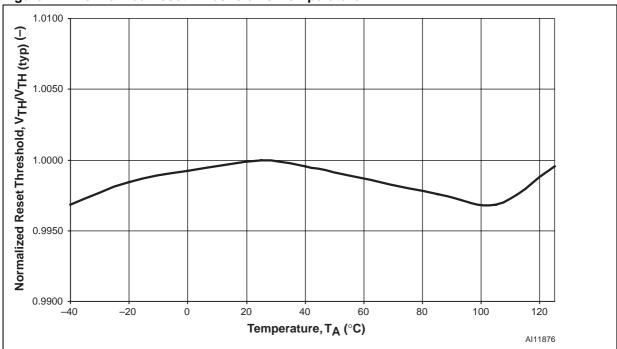


Figure 12. Normalized Reset Threshold vs. Temperature



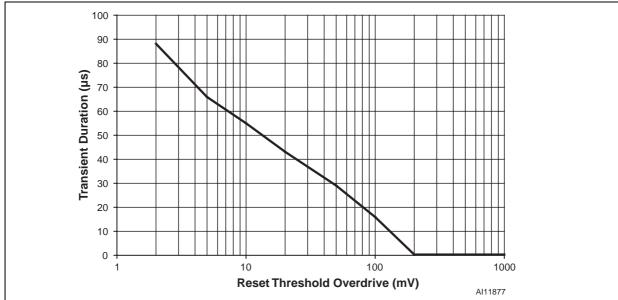


Figure 13. Max. Transient Duration NOT Causing Reset Pulse vs. Reset Threshold Overdrive

Note: Reset occurs above the curve.

STM6315 4 Maximum Rating

4 Maximum Rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 2. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
	Operating Temperature Range	-40 to 125	
T _{STG}	Storage Temperature (V _{CC} Off)	-55 to 150	°C
T _{SLD} ⁽¹⁾	Lead Solder Temperature for 10 seconds	260	°C
V _{IO}	Input or Output Voltage	-0.3 to V_{CC} + 0.3	V
V _{CC}	Supply Voltage	-0.3 to 7.0	V
I _O	Output Current	20	mA
P _D	Power Dissipation	320	mW

^{1.} Reflow at peak temperature of 260°C (total thermal budget not to exceed 245°C for greater than 30 seconds).

5 DC and AC Parameters STM6315

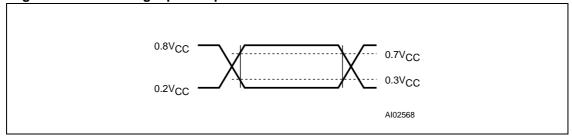
5 DC and AC Parameters

This section summarizes the operating measurement conditions, and the DC and AC characteristics of the device. The parameters in the DC and AC characteristics Tables that follow are derived from tests performed under the Measurement Conditions summarized in *Table 3*, Operating and AC Measurement Conditions. Designers should check that the operating conditions in their circuit match the operating conditions when relying on the quoted parameters.

Table 3. Operating and AC Measurement Conditions

Parameter	STM6315	Unit
V _{CC} Supply Voltage	1.0 to 5.5	V
Ambient Operating Temperature (T _A)	-40 to +125	°C
Input Rise and Fall Times	~5	ns
Input Pulse Voltages	0.2 to 0.8V _{CC}	V
Input and Output Timing Reference Voltages	0.3 to 0.7V _{CC}	V

Figure 14. AC Testing Input/Output Waveforms



STM6315 5 DC and AC Parameters

Table 4. DC and AC Characteristics

Sym	Alter- native	Description		Test Condition ⁽¹⁾	Min	Тур	Max	Unit
V_{CC}		Operating V	oltage	$T_A = -40 \text{ to } +85^{\circ}\text{C}$	1.0		5.5	V
				$V_{CC} = 5.5V$, No load $T_A = -40$ to $+85^{\circ}C$		5	12	μA
,		V Cumhi	Current	$V_{CC} = 5.5V$, No load $T_{A} = -40 \text{ to } +125^{\circ}\text{C}$			15	μA
I _{CC}		V _{CC} Supply	Current	$V_{CC} = 3.6V$, No load $T_A = -40$ to $+85$ °C		4	10	μA
				$V_{CC} = 3.6V$, No load $T_{A} = -40$ to +125°C			12	μA
				V _{CC} > 4.25V, I _{SINK} = 3.2mA			0.4	V
V_{OL}		RST Output	Voltage	V _{CC} > 2.5V, I _{SINK} = 1.2mA			0.3	V
				$V_{CC} > 1.0V$, $I_{SINK} = 80\mu A$			0.3	V
		RST Output Leakage Cu	Open Drain irrent	$V_{CC} > V_{RST}$, RST not asserted			1	μA
Reset	Thresho	lds						
				V _{CC} falling; T _A = 25°C	V _{RST} x 0.982	0.982 2.63	V _{RST} x 1.018	V
V _{RST}		Reset Thres	shold	V_{CC} falling; $T_A = -40^{\circ}$ to 85°C	V _{RST} x 0.975	2.93 3.08 4.38	V _{RST} x 1.025	٧
				V_{CC} falling; $T_A = -40^{\circ}$ to 125°C	V _{RST} x 0.965	4.63	V _{RST} x 1.035	V
				V _{CC} falling from				
t_{RD}		V _{CC} -to-RST	Delay	(V _{RST} + 100mV) to		35		μs
				(V _{RST} – 200mV) @ 10mV/μs				
			STM6315xAxxxx	$T_A = -40 \text{ to } +85^{\circ}\text{C}$	1	1.5	2	ms
				$T_A = -40 \text{ to } +125^{\circ}\text{C}$	0.8	1.5	2.4	ms
			CTM621EvPyggg	$T_A = -40 \text{ to } +85^{\circ}\text{C}$	20	30	40	ms
	+	RST Pulse	STM6315xBxxxx	$T_A = -40 \text{ to } +125^{\circ}\text{C}$	16	30	48	ms
	t _{rec}	Width	STM6315xDxxxx	$T_A = -40 \text{ to } +85^{\circ}\text{C}$	140	040	280	ms
				$T_A = -40 \text{ to } +125^{\circ}\text{C}$	112	210	336	ms
			CTMC245::C:	$T_A = -40 \text{ to } +85^{\circ}\text{C}$	1120	1600	2240	ms
			STM6315xGxxxx	$T_A = -40 \text{ to } +125^{\circ}\text{C}$	896	1680	2688	ms
		Reset Thres Coefficient	shold Temperature			60		ppm/ °C

5 DC and AC Parameters STM6315

Sym	Alter- native	Description	Test Condition ⁽¹⁾	Min	Тур	Max	Unit
Manua	l Reset I	nput					
V		MD I avv lagget Throughold	V _{RST} > 4.0V	0.8			V
V _{IL}		MR Low Input Threshold	V _{RST} < 4.0V	0.3V _{CC}			V
\/	MD I am land Thank a	MD I avv lanut Threehold	V _{RST} > 4.0V			2.4	V
V _{IH}		MR Low Input Threshold	V _{RST} < 4.0V			0.7V _{CC}	V
		MR Input Pulse Width		1			μs
		MR Glitch Rejection			100		ns
		MR-to-RST Delay			500		ns
		MR Pull-up Resistance		32	63	100	kΩ

^{1.} Valid for Ambient Operating Temperature: $T_A = -40$ to 125°C; $V_{CC} = 2.5$ V to 5.5V (except where noted).

STM6315 6 Package Mechanical

6 Package Mechanical

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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6 Package Mechanical STM6315

Figure 15. SOT143-4 – 4-lead Small Outline Transistor Package Outline

Drawing is not to scale.

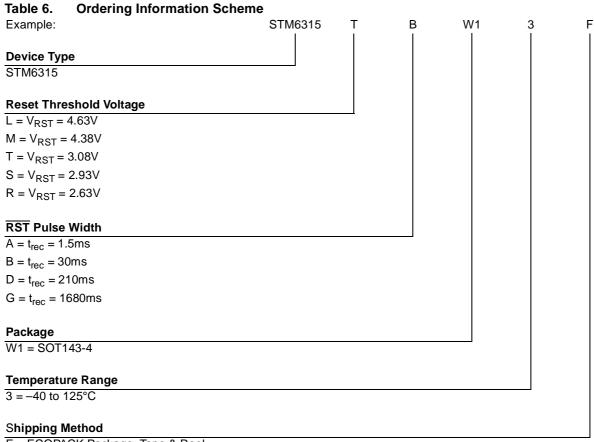
SOT143-4z⁽¹⁾

Table 5. SOT143-4 – 4-lead Small Outline Transistor Package Mechanical Data

Coursels ad		mm		inches		
Symbol	Тур	Min	Max	Тур	Min	Max
А	-	0.89	1.12	_	0.035	0.044
A1	-	0.01	0.10	_	0.001	0.004
A2	_	0.88	1.02	-	0.035	0.042
b	-	0.37	0.51	-	0.015	0.020
b2	_	0.76	0.94	-	0.030	0.037
С	-	0.09	0.18	-	0.004	0.007
D	_	2.80	3.04	_	0.110	0.120
E	-	2.10	2.64	-	0.083	0.104
E1	-	1.20	1.40	-	0.047	0.055
е	1.92	-	-	0.076	_	_
e1	0.20	-	-	0.008	-	_
L	0.55	-	-	0.022	-	_
L1	-	0.40	0.60	_	0.016	0.024
Θ		0°	10°		0°	10°
N		4			4	

STM6315 7 Part Numbering

7 Part Numbering



F = ECOPACK Package, Tape & Reel

Note: For other options, or for more information on any aspect of this device, please contact the ST Sales Office nearest you.

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7 Part Numbering STM6315

Table 7. Marking Description

Part Number	Reset Threshold	RST Pulse Width	Output	Topside Marking
STM6315LA	4.63	1.5	Open-drain RST	9LAx
STM6315MA	4.38	1.5	Open-drain RST	9MAx
STM6315TA	3.08	1.5	Open-drain RST	9TAx
STM6315SA	2.93	1.5	Open-drain RST	9SAx
STM6315RA	2.63	1.5	Open-drain RST	9RAx
STM6315LB	4.63	30	Open-drain RST	9LBx
STM6315MB	4.38	30	Open-drain RST	9MBx
STM6315TB	3.08	30	Open-drain RST	9TBx
STM6315SB	2.93	30	Open-drain RST	9SBx
STM6315RB	2.63	30	Open-drain RST	9RBx
STM6315LD	4.63	210	Open-drain RST	9LDx
STM6315MD	4.38	210	Open-drain RST	9MDx
STM6315TD	3.08	210	Open-drain RST	9TDx
STM6315SD	2.93	210	Open-drain RST	9SDx
STM6315RD	2.63	210	Open-drain RST	9RDx
STM6315LG	4.63	1680	Open-drain RST	9LGx
STM6315MG	4.38	1680	Open-drain RST	9MGx
STM6315TG	3.08	1680	Open-drain RST	9TGx
STM6315SG	2.93	1680	Open-drain RST	9SGx
STM6315RG	2.63	1680	Open-drain RST	9RGx

STM6315 8 Revision History

8 Revision History

Table 8. Document Revison History

Date	Revision	Description
14-November-2005	1.0	First edition

8 Revision History STM6315

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